# **UNR31A9**

## Silicon PNP epitaxial planar type

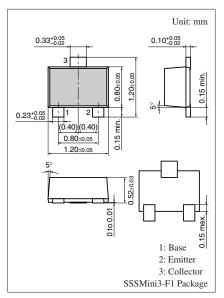
### For digital circuits

### ■ Features

- Suitable for high-density mounting downsizing of the equipment
- Contribute to low power consumption

## ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                             | Symbol           | Rating      | Unit |  |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -50         | V    |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -50         | V    |  |
| Collector current                     | $I_C$            | -80         | mA   |  |
| Total power dissipation               | P <sub>T</sub>   | 100         | mW   |  |
| Junction temperature                  | $T_{j}$          | 125         | °C   |  |
| Storage temperature                   | $T_{stg}$        | -55 to +125 | °C   |  |



Marking Symbol: DC

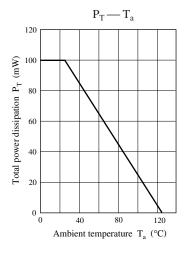
#### Internal Connection

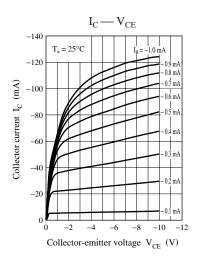
$$\begin{array}{c}
R_1 (1 k\Omega) \\
B \circ \longrightarrow W \\
R_2 \\
(10 k\Omega) \\
\end{array}$$

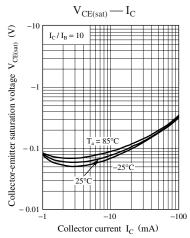
## ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

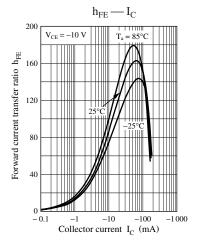
| Parameter                                    | Symbol               | Conditions   | Min  | Тур  | Max    | Unit |
|--|----------------------|--|------|------|--------|------|
| Collector-base voltage (Emitter open)        | V <sub>CBO</sub>     | $I_C = -10 \ \mu A, I_E = 0$   | -50  |      |        | V    |
| Collector-emitter voltage (Base open)        | V <sub>CEO</sub>     | $I_C = -2 \text{ mA}, I_B = 0$   | -50  |      |        | V    |
| Collector-base cutoff current (Emitter open) | $I_{CBO}$            | $V_{CB} = -50 \text{ V}, I_E = 0$                                      |      |      | - 0.1  | μΑ   |
| Collector-emitter cutoff current (Base open) | $I_{CEO}$            | $V_{CE} = -50 \text{ V}, I_{B} = 0$                                    |      |      | - 0.5  | μΑ   |
| Emitter-base cutoff current (Collector open) | I <sub>EBO</sub>     | $V_{EB} = -6 \text{ V}, I_C = 0$                                       |      |      | -1.5   | mA   |
| Forward current transfer ratio               | $h_{FE}$             | $V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$                        | 30   |      |        | _    |
| Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$                          |      |      | - 0.25 | V    |
| Output voltage high-level                    | V <sub>OH</sub>      | $V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | -4.9 |      |        | V    |
| Output voltage low-level                     | V <sub>OL</sub>      | $V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$ |      |      | - 0.2  | V    |
| Input resistance                             | R <sub>1</sub>       |  | -30% | 1    | +30%   | kΩ   |
| Resistance ratio                             | $R_1/R_2$            |  | 0.08 | 0.10 | 0.12   |      |
| Transition frequency                         | $f_T$                | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$      |      | 80   |        | MHz  |

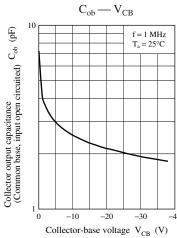
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

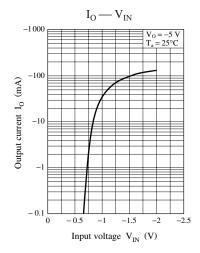


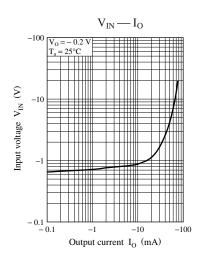












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